

RF Power Amplifier module

AP1100 - 1

This solid state power amplifier is designed for reliable, trouble-free service. It operates in a class A with a 26 V DC power supply. The amplifier is accommodated in aluminium housing.

Features :

- * 2,5 Watts saturated output power
- * 30 dB minimum gain
- * Electronic Attenuator in option
- * Overvoltage and reverse protection

Applications :

- * RF links
- * Test Bench
- * Field Test
- * Instrumentation

Specifications

Characteristics	Data	Units
Frequency range	1 MHz - 100 MHz	MHz
RF output power CW		
Typ.	1,5	W
Min	1	W
Class	A	
Power gain	30	dB
Flatness	+/-2 dB	dB
Input power for rated output power	0	dBm
Max. input power	10	dBm
In / Out impedances nom.	50	Ohms
Input VSWR	2 : 1	
Load VSWR for rated output power	up to 1.5 : 1	
VSWR mismatch	Infinite @ 1 W	
Protection circuits	Load VSWR, over temperature	
Harmonics typ.	-20	dBc
Spurious typ.	-60	dBc
Modulation capability	100	%
Noise Figure typ.	10	dB
Intercept point 3 rd Order typ.	38	dBm
RF connectors	N female	
Cooling	by conduction	
Operating temperature Range	0 °C ... + 55	° C
Power Supply	26 DC +/- 5%	V
Dimensions (W x L x H)	135 x 100 x 41	mm
All data at room temperature + 22 °C, into 50 Ohms, subject to change without notice		

Made in European Union

11/09/2001

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